

产品描述

SOT-89 PNP Silicon PNP transistor in a SOT-89 Plastic Package.

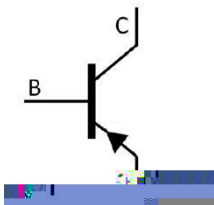
主要特性

1. $I_{CE(sat)}$ 2SD1766
 Low $V_{CE(sat)}$, complements the 2SD1766.

应用

Medium power amplifier applications.

封装与引脚



封装与引脚



PIN1 Base PIN 2 Collector PIN 3 Emitter

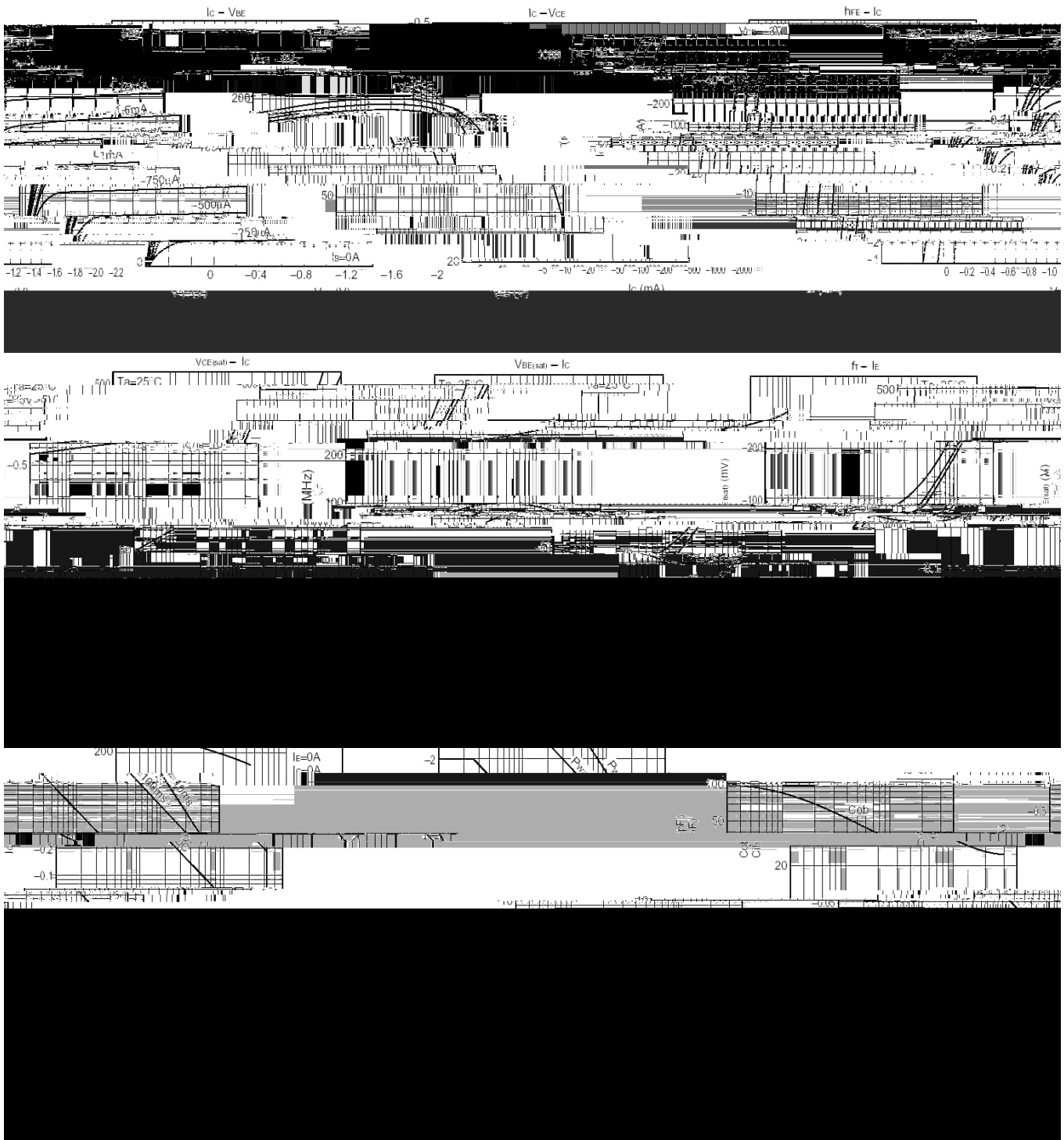
电气特性

h_{FE} Classifications Symbol	P	Q	R
h_{FE} Range	82 180	120 270	180 390
Marking	HBCP	HBCQ	HBCR

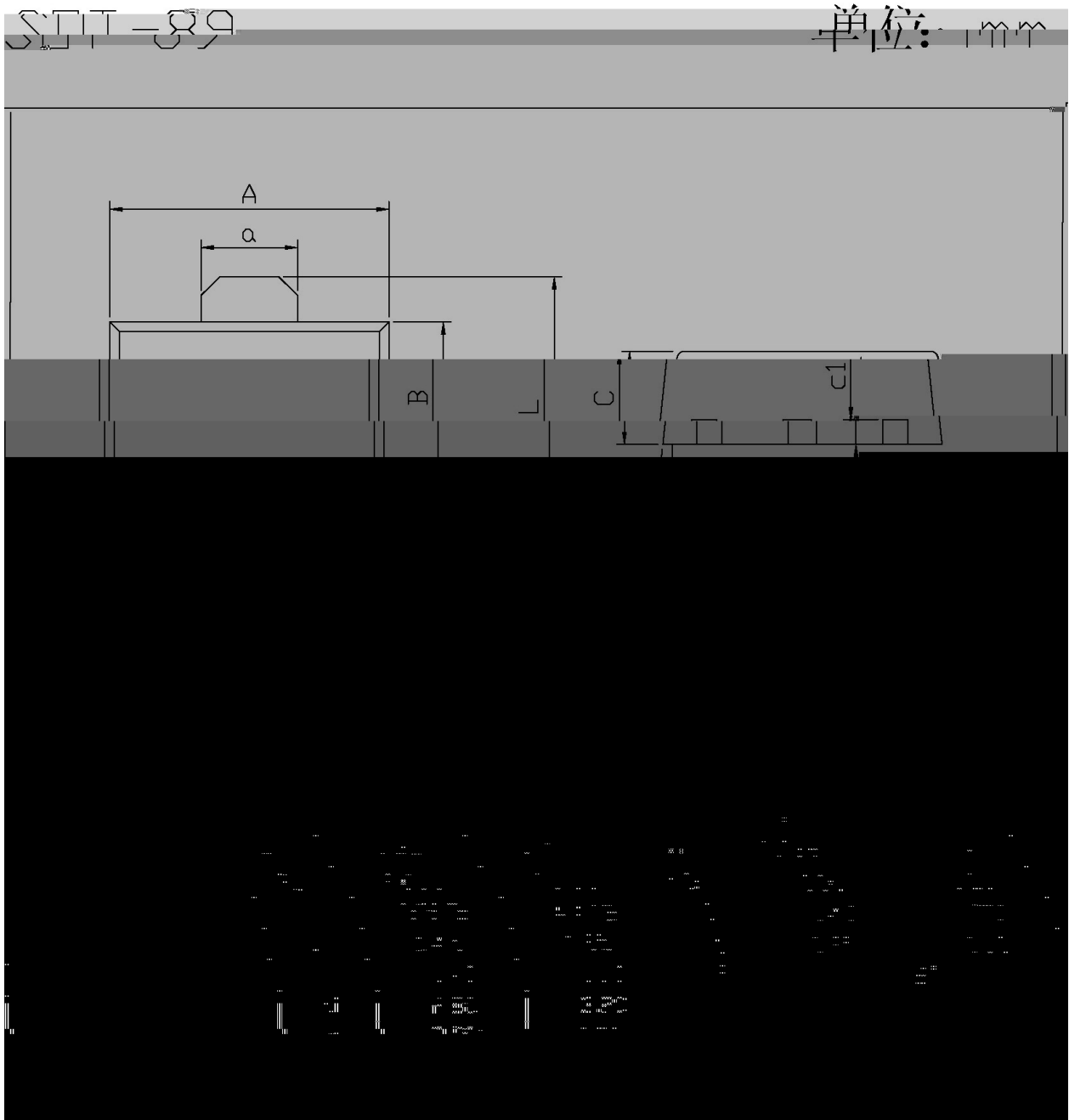
Parameter	Symbol	Rating	Unit
Collector to Base Voltage	V_{CBO}	-40	V

Colle

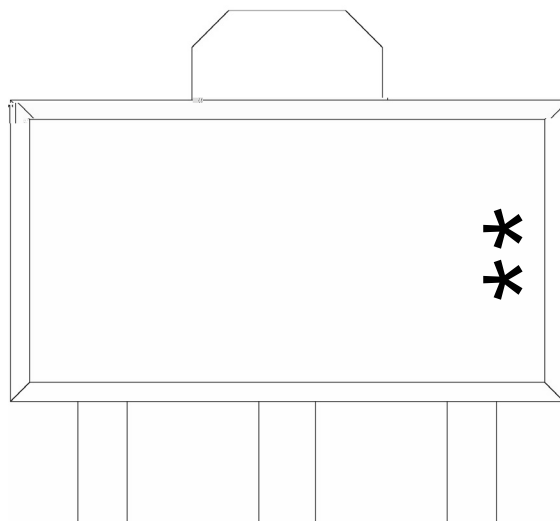
三极管



单位: mm



1. 1



H

BC

P h_{FE}

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Note:

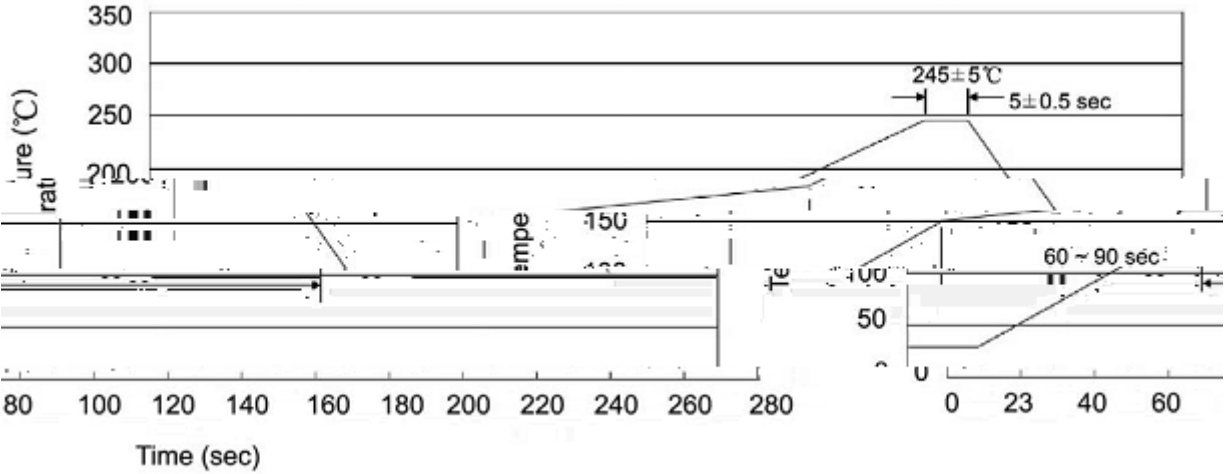
H: Company Code.

BC: Product Type.

P h_{FE} Classifications Symbol

**: Lot No. Code, code change with Lot No.

Whp shudwxuh Suriloh i ru LU Uhior z Vroghulq j+Se0l uhh,



Note:

- 1251506090sec;

2245±55±0.5sec;

3210 /sec.
- 1.Preheating:25~150 , Time:60~90sec.

2.Peak Temp.:245±5 , Duration:5±0.5sec.

3. Cooling Speed: 2~10 /sec.

1 0 q 1 Y T

260±510±1 sec.Temp.:260±5Time:10±1 sec

9 E 1

/ REEL

Package Type 封装形式	Units 包装数量					Dimension 包装尺寸 (unit: mm ³)		
	Units/Reel 只/卷盘	Reels/Inner Box 卷盘/盒	Units/Inner Box 只/盒	Inner Boxes/Outer Box 盒/箱	Units/Outer Box 只/箱	Reel	Inner Box 盒	Outer Box 箱
SOT-89	1,000	7	7,000	8	56,000	7 ×12	180×120×180	385×257×392

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